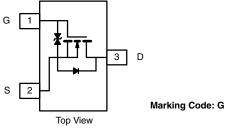


Vishay Siliconix

N-Channel 1.5 V (G-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (mA)		
20	5 at V _{GS} = 4.5 V	200		
	7 at V _{GS} = 2.5 V	175		
	9 at V _{GS} = 1.8 V	150		
	10 at V _{GS} = 1.5 V	50		

SC-75A or SC-89



Ordering Information:

Si1032R-T1-GE3 (SC-75A, Lead (Pb)-free and Halogen-free) Si1032X-T1-GE3 (SC-89, Lead (Pb)-free -free Halogen-free)

FEATURES

- Halogen-free According to IEC 61249-2-21
 Definition
- Low-Side Switching
- Low On-Resistance: 5 Ω
- Low Threshold: 0.9 V (typ.)
- Fast Switching Speed: 35 ns
- TrenchFET[®] Power MOSFETs: 1.5 V Rated
- 2000 V ESD Protection
- Compliant to RoHS Directive 2002/95/EC

BENEFITS

- Ease in Driving Switches
- · Low Offset (Error) Voltage
- Low-Voltage Operation
- High-Speed Circuits
- Low Battery Voltage Operation

APPLICATIONS

- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories
- Battery Operated Systems
- Power Supply Converter Circuits
- · Load/Power Switching Cell Phones, Pagers

Parameter		Symbol	Si1032R		Si1032X		
			5 s	Steady State	5 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	20				v
Gate-Source Voltage		V _{GS}	± 6				
	T _A = 25 °C		200	140	210	200	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 85 °C		110	100	150	140	
Pulsed Drain Current ^a		I _{DM}		500	600		mA
Continuous Source Current (Diode Conduction) ^a		۱ _S	250	200	300	240	
	T _A = 25 °C	Б	280	250	340	300	mW
Maximum Power Dissipation ^a for SC-75	T _A = 85 °C	P _D	145	130	170	150	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150				°C
Gate-Source ESD Rating (HBM, Method 3015)		ESD	2000				V

Notes:

a. Surface mounted on FR4 board.

FREE

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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	0.40	0.7	1.2	V	
Gate-Body Leakage	I _{GSS} -	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 2.8 \text{ V}$		± 0.5	± 1.0	± 1.0	
		$V_{DS} = 0 V, V_{GS} = \pm 4.5 V$		± 1.0	± 3.0		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 20 V, V_{GS} = 0 V$			1	μA	
		V_{DS} = 20 V, V_{GS} = 0 V, T_{J} = 55 °C	20 V, V _{GS} = 0 V, T _J = 55 °C		10		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = 5 V, V_{GS} = 4.5 V$	250			mA	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 200 \text{ mA}$			5	5	
		V _{GS} = 2.5 V, I _D = 175 mA			7	0	
		V _{GS} = 1.8 V, I _D = 150 mA			9	Ω	
		V _{GS} = 1.5 V, I _D = 40 mA			10		
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 200 \text{ mA}$		0.5		S	
Diode Forward Voltage ^a	V _{SD}	I _S = 150 mA, V _{GS} = 0 V			1.2	V	
Dynamic ^b							
Total Gate Charge	Qg			750			
Gate-Source Charge	Q _{gs}	V_{DS} = 10 V, V_{GS} = 4.5 V, I_D = 250 mA		75		рС	
Gate-Drain Charge	Q _{gd}			225			
Turn-On Delay Time	t _{d(on)}				50		
Rise Time	t _r	V_{DD} = 10 V, R_L = 47 Ω			25		
Turn-Off Delay Time	t _{d(off)}	$\rm I_D \cong 200~mA,~V_{GEN}$ = 4.5 V, $\rm R_g$ = 10 Ω			50	ns	
Fall Time	t _f				25		

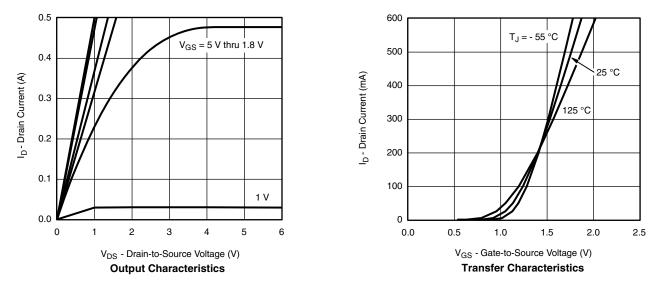
Notes:

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

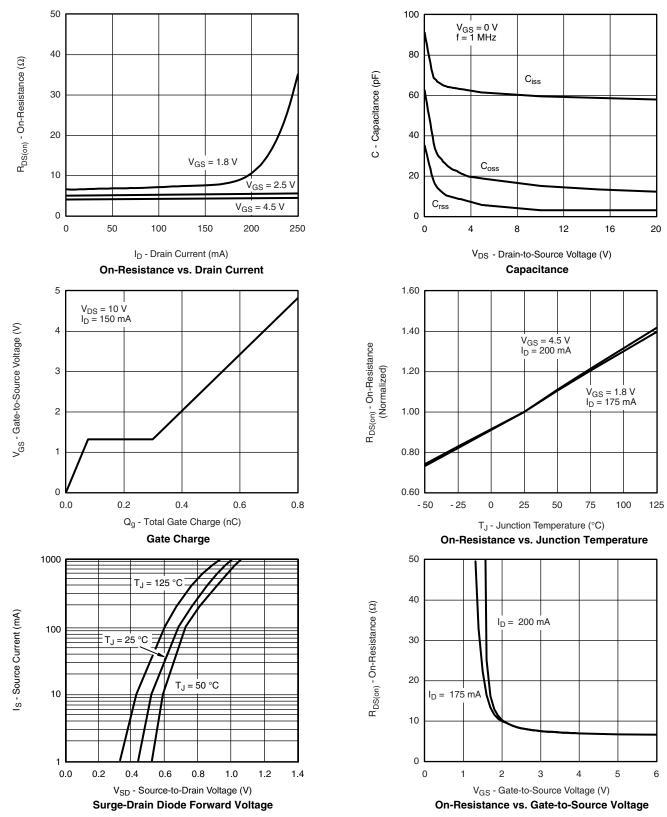
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.







TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Document Number: 71172 S10-2544-Rev. F, 08-Nov-10

Si1032R/X

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0.0

- 0.1

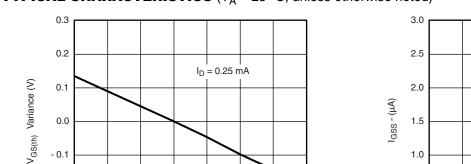
- 0.2

- 0.3

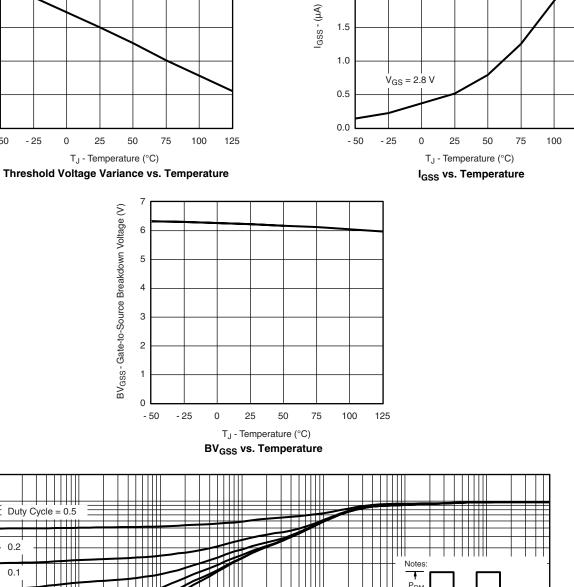
2 1

- 50

- 25



TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Normalized Effective Transient Thermal Impedance 0.2 0.1 P_{DM} 0.1 0.05 t₁ t2 0.02 t₁ 1. Duty Cycle, D = t₂ 2. Per Unit Base = RthJA = 500 °C/W 3. $T_{JM} - T_A = P_{DM}Z_{thJA}^{(t)}$ Single Pulse 4. Surface Mounted 0.01 10-4 10⁻³ 10⁻² 10-1 1 10 100 600 Square Wave Pulse Duration (s)

Normalized Thermal Transient Impedance, Junction-to-Ambient (SC-75A, Si1032R Only)

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71172.

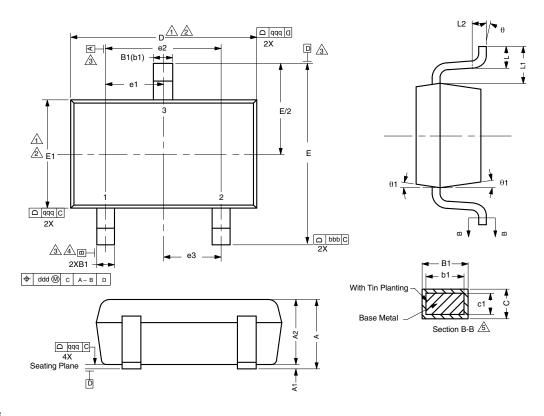


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SC-75A: 3 Leads



DWG: 5868

Notes

Dimensions in millimeters will govern.

- ⚠Dimension D does not include mold flash, protrusions or gate burrs. Mold flash protrusions or gate burrs shall not exceed 0.10 mm per end. Dimension E1 does not include Interlead flash or protrusion. Interlead flash or protrusion shall not exceed 0.10 mm per side.
- 2 Dimensions D and E1 are determined at the outmost extremes of the plastic body exclusive of mold flash, tie bar burrs, gate burrs and interlead flash, but including any mismatch between the top and bottom of the plastic body.
- A Datums A, B and D to be determined 0.10 mm from the lead tip.

A Terminal positions are shown for reference only.

These dimensions apply to the flat section of the lead between 0.08 mm and 0.15 mm from the lead tip.

DIMENSIONS	TOLERANCES		
aaa	0.10		
bbb	0.10		
ссс	0.10		
ddd	0.10		

DIM.	P	NOTE		
Divi.	MIN.	NOM.	MAX.	NOTE
А	-	-	0.80	
A1	0.00	-	0.10	
A2	0.65	0.70	0.80	
B1	0.19	-	0.24	5
b1	0.17	-	0.21	
с	0.13	-	0.15	5
c1	0.10	-	0.12	5
D	1.48	1.575	1.68	1, 2
E	1.50	1.60	1.70	
E1	0.66	0.76	0.86	1, 2
e1	0.50 BSC			
e2	1.00 BSC			
e3				
L	0.15	0.205	0.30	
L1				
L2				
q	0°	-	8°	
q1	4°	-	10°	

C15-1445-Rev. F, 23-Nov-15

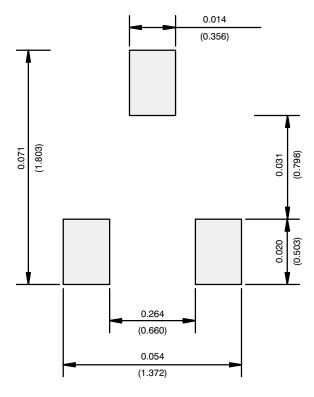
1



Application Note 826

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RECOMMENDED MINIMUM PADS FOR SC-75A: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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